# SIMON FRASER UNIVERSITY SCHOOL OF ENGINEERING SCIENCE

# Fall 2014 ENSC 220: ELECTRIC CIRCUITS I

# Final Examination Friday, December 12, 2014

Duration: 180 minutes. Attempt all problems. Questions are not equally weighted. Closed book and closed notes. Simple calculators (with no graphing/programming functions) are permitted. PDAs, laptops, and wireless phones are not permitted. Please show details of your work and derive all equations and expressions. Please write legibly. Illegible text will not be graded. Use a ball-point pen for writing the examination (no pencils, please).

#### 1. (10 points)

For the circuit shown in Figure 1:

- (a) Find the Thévenin voltage.
- (b) Find the Thévenin resistance.

### 2. (35 points)

The circuit shown in Figure 2 is a leaky integrator, which contains an deal op-amp. The input for all time is  $v_s(t) = -5u(t)$ .  $R_2$  represents the leakage resistance of the capacitor.

- (a) Given C and  $R_2$ , choose the resistance  $R_1$  to achieve the overall gain of 10.
- (b) Find response  $v_{out}(t)$  assuming  $v_c(0^-) = 0$ .
- (c) Find the response of the ideal (non-leaky) integrator.
- (d) Sketch and compare the responses of the leaky and ideal integrators.

### 3. (35 points)

Consider the circuit shown in Figure 3:

- (a) Write the state equations.
- (b) Write a second-order differential equation with  $v_c$  as the unknown.
- (c) Find the roots of the characteristic equation.
- (d) Specify the response of the circuit for the given values of circuit parameters.
- (e) If  $v_{in}(t) = u(t) V$ , find  $v_C(t)$  for t > 0.

### 4. (20 points)

In the circuit shown in Figure 4,  $v_s(t) = \sqrt{2} \ 100 \ cos(300t + 30^\circ) \ V$ .

- (a) Find  $i_L(t)$ .
- (b) Find the complex and average power absorbed by the laod.

